

## 限用物質及其化學符號

設備名稱：隨身碟		， 型號（型式）：LU202W128G（型號列表如附件）				
Equipment name		Type designation (Type)				
單元 Unit	限用物質及其化學符號					
	Restricted substances and its chemical symbols					
	鉛Lead (Pb)	汞Mercury (Hg)	鎘Cadmium (Cd)	六價鉻 Hexavalent chromium (Cr <sup>+6</sup> )	多溴聯苯 Polybrominated biphenyls (PBB)	多溴二苯醚 Polybrominated diphenyl ethers (PBDE)
基板 COB	○	○	○	○	○	○
外殼 Casing	○	○	○	○	○	○
積體電路 IC	○	○	○	○	○	○
被動元件 Passive Component	—	○	○	○	○	○
<p>備考1. “超出0.1wt%”及“超出0.01wt%”係指限用物質之百分比含量超出百分比含量基準值。            Note 1 : “Exceeding 0.1 wt %” and “exceeding 0.01 wt %” indicate that the percentage content of the restricted substance exceeds the reference percentage value of presence condition.</p> <p>備考2. “○”係指該項限用物質之百分比含量未超出百分比含量基準值。            Note 2 : “○” indicates that the percentage content of the restricted substance does not exceed the percentage of reference value of presence.</p> <p>備考3. “—”係指該項限用物質為排除項目對應CNS15663 附錄D 排除項目D16。            Note 3 : The “—” indicates that the restricted substance corresponds to the exemption and base on D16 of Annex D of CNS15663.</p>						

型號： LU202W128G, LU202W064G, LU202W032G, LU202W016G,  
 LU202L128G, LU202L064G, LU202L032G, LU202L016G

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設備名稱：隨身碟		， 型號（型式）：LU203W128G（型號列表如附件）				
Equipment name		Type designation (Type)				
單元 Unit	限用物質及其化學符號					
	Restricted substances and its chemical symbols					
	鉛Lead (Pb)	汞Mercury (Hg)	鎘Cadmium (Cd)	六價鉻 Hexavalent chromium (Cr <sup>+6</sup> )	多溴聯苯 Polybrominated biphenyls (PBB)	多溴二苯醚 Polybrominated diphenyl ethers (PBDE)
基板 COB	○	○	○	○	○	○
外殼 Casing	○	○	○	○	○	○
積體電路 IC	○	○	○	○	○	○
被動元件 Passive Component	—	○	○	○	○	○
<p>備考1. “超出0.1wt%”及“超出0.01wt%”係指限用物質之百分比含量超出百分比含量基準值。            Note 1 : “Exceeding 0.1 wt %” and “exceeding 0.01 wt %” indicate that the percentage content of the restricted substance exceeds the reference percentage value of presence condition.</p> <p>備考2. “○”係指該項限用物質之百分比含量未超出百分比含量基準值。            Note 2 : “○” indicates that the percentage content of the restricted substance does not exceed the percentage of reference value of presence.</p> <p>備考3. “—”係指該項限用物質為排除項目對應CNS15663 附錄D 排除項目D16。            Note 3 : The “—” indicates that the restricted substance corresponds to the exemption and base on D16 of Annex D of CNS15663.</p>						

型號： LU203W128G, LU203W064G, LU203W032G, LU203W016G

## 限用物質及其化學符號

設備名稱：隨身碟		， 型號（型式）： LU301W256G（型號列表如附件）				
Equipment name		Type designation (Type)				
單元 Unit	限用物質及其化學符號					
	Restricted substances and its chemical symbols					
	鉛Lead (Pb)	汞Mercury (Hg)	鎘Cadmium (Cd)	六價鉻 Hexavalent chromium (Cr <sup>+6</sup> )	多溴聯苯 Polybrominated biphenyls (PBB)	多溴二苯醚 Polybrominated diphenyl ethers (PBDE)
基板 COB	○	○	○	○	○	○
外殼 Casing	○	○	○	○	○	○
積體電路 IC	○	○	○	○	○	○
被動元件 Passive Component	—	○	○	○	○	○
<p>備考1. “超出0.1wt%”及“超出0.01wt%”係指限用物質之百分比含量超出百分比含量基準值。            Note 1 : “Exceeding 0.1 wt %” and “exceeding 0.01 wt %” indicate that the percentage content of the restricted substance exceeds the reference percentage value of presence condition.</p> <p>備考2. “○”係指該項限用物質之百分比含量未超出百分比含量基準值。            Note 2 : “○” indicates that the percentage content of the restricted substance does not exceed the percentage of reference value of presence.</p> <p>備考3. “—”係指該項限用物質為排除項目對應CNS15663 附錄D 排除項目D16。            Note 3 : The “—” indicates that the restricted substance corresponds to the exemption and base on D16 of Annex D of CNS15663.</p>						

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 LU301W016G,  
 LU301L256G, LU301L128G, LU301L064G, LU301L032G,  
 LU301K256G, LU301K128G, LU301K064G, LU301K032G,  
 LU301A256G, LU301A128G, LU301A064G, LU301A032G,  
 LU301B256G, LU301B128G, LU301B064G, LU301B032G,  
 LU301C256G, LU301C128G, LU301C064G, LU301C032G

## 限用物質及其化學符號

設備名稱：隨身碟		， 型號（型式）：LU365K256G（型號列表如附件）				
Equipment name		Type designation (Type)				
單元 Unit	限用物質及其化學符號					
	Restricted substances and its chemical symbols					
	鉛Lead (Pb)	汞Mercury (Hg)	鎘Cadmium (Cd)	六價鉻 Hexavalent chromium (Cr <sup>+6</sup> )	多溴聯苯 Polybrominated biphenyls (PBB)	多溴二苯醚 Polybrominated diphenyl ethers (PBDE)
基板 COB	○	○	○	○	○	○
外殼 Casing	○	○	○	○	○	○
積體電路 IC	○	○	○	○	○	○
被動元件 Passive Component	—	○	○	○	○	○
<p>備考1. “超出0.1wt%”及“超出0.01wt%”係指限用物質之百分比含量超出百分比含量基準值。            Note 1 : “Exceeding 0.1 wt %” and “exceeding 0.01 wt %” indicate that the percentage content of the restricted substance exceeds the reference percentage value of presence condition.</p> <p>備考2. “○”係指該項限用物質之百分比含量未超出百分比含量基準值。            Note 2 : “○” indicates that the percentage content of the restricted substance does not exceed the percentage of reference value of presence.</p> <p>備考3. “—”係指該項限用物質為排除項目對應CNS15663 附錄D 排除項目D16。            Note 3 : The “—” indicates that the restricted substance corresponds to the exemption and base on D16 of Annex D of CNS15663.</p>						

型號： LU365K256G, LU365K128G, LU365K064G, LU365K032G

## 限用物質及其化學符號

設備名稱：隨身碟		， 型號（型式）：LU366S128G（型號列表如附件）				
Equipment name		Type designation (Type)				
單元 Unit	限用物質及其化學符號					
	Restricted substances and its chemical symbols					
	鉛Lead (Pb)	汞Mercury (Hg)	鎘Cadmium (Cd)	六價鉻 Hexavalent chromium (Cr <sup>+6</sup> )	多溴聯苯 Polybrominated biphenyls (PBB)	多溴二苯醚 Polybrominated diphenyl ethers (PBDE)
基板 COB	○	○	○	○	○	○
外殼 Casing	○	○	○	○	○	○
積體電路 IC	○	○	○	○	○	○
被動元件 Passive Component	—	○	○	○	○	○
<p>備考1. “超出0.1wt%”及“超出0.01wt%”係指限用物質之百分比含量超出百分比含量基準值。            Note 1 : “Exceeding 0.1 wt %” and “exceeding 0.01 wt %” indicate that the percentage content of the restricted substance exceeds the reference percentage value of presence condition.</p> <p>備考2. “○”係指該項限用物質之百分比含量未超出百分比含量基準值。            Note 2 : “○” indicates that the percentage content of the restricted substance does not exceed the percentage of reference value of presence.</p> <p>備考3. “—”係指該項限用物質為排除項目對應CNS15663 附錄D 排除項目D16。            Note 3 : The “—” indicates that the restricted substance corresponds to the exemption and base on D16 of Annex D of CNS15663.</p>						

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## 限用物質及其化學符號

設備名稱：隨身碟		， 型號（型式）：LU401S064G（型號列表如附件）				
Equipment name		Type designation (Type)				
單元 Unit	限用物質及其化學符號					
	Restricted substances and its chemical symbols					
	鉛Lead (Pb)	汞Mercury (Hg)	鎘Cadmium (Cd)	六價鉻 Hexavalent chromium (Cr <sup>+6</sup> )	多溴聯苯 Polybrominated biphenyls (PBB)	多溴二苯醚 Polybrominated diphenyl ethers (PBDE)
基板 COB	○	○	○	○	○	○
外殼 Casing	○	○	○	○	○	○
積體電路 IC	○	○	○	○	○	○
被動元件 Passive Component	—	○	○	○	○	○
<p>備考1. “超出0.1wt%”及“超出0.01wt%”係指限用物質之百分比含量超出百分比含量基準值。            Note 1 : “Exceeding 0.1 wt %” and “exceeding 0.01 wt %” indicate that the percentage content of the restricted substance exceeds the reference percentage value of presence condition.</p> <p>備考2. “○”係指該項限用物質之百分比含量未超出百分比含量基準值。            Note 2 : “○” indicates that the percentage content of the restricted substance does not exceed the percentage of reference value of presence.</p> <p>備考3. “—”係指該項限用物質為排除項目對應CNS15663 附錄D 排除項目D16。            Note 3 : The “—” indicates that the restricted substance corresponds to the exemption and base on D16 of Annex D of CNS15663.</p>						

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